## NSN 5961-00-052-7874

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View Online at https://aerobasegroup.com/nsn/5961-00-052-7874 **Inclosure Material:** Metal **Overall Length:** 0.297 inches **Overall Diameter:** 0.620 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 6.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 2.50 amperes source cutoff current and 1.00 amperes collector current, dc **Power Rating Per Characteristic:** 20.0 watts collector power dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: